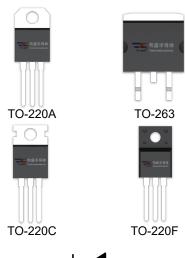


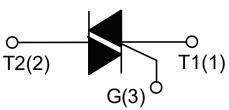
DESCRIPTION:

The BT139X-600F SCR series with the parallel resistor between Gate and Cathode are especially recommended for use on straight hair, igniter, anion generator, etc.



MAIN FEATURES

Symbol	Value	Unit
I _{T(RMS)}	16	А
V _{DRM} /V _{RRM}	600 and 800	V



ABSOLUTE MAXIMUM RATINGS

Parameter		Symbol	Value	Unit
Storage junction temperature range		T _{stg}	-40-150	$^{\circ}\!\mathbb{C}$
Operating junction temperature range		Tj	-40-125	$^{\circ}\!\mathbb{C}$
Repetitive peak off-sta	te voltage(Tj=25℃)	V _{DRM}	600/800	V
Repetitive peak reverse voltage(T _j =25℃)		V _{RRM}	600/800	V
Non repetitive surge peak Off-state voltage		V _{DSM}	V _{DRM} + 100	V
Non repetitive peak reverse voltage		V _{RSM}	V _{RRM} + 100	V
RMS on-state current	TO-220C(Tc=100°C)		16	
	TO-220F(Ins) (Tc=85℃)			А
	TO-263 (T _C =75°C)	T _(RMS)		
	TO-220A(Ins) (Tc=87℃)			
Non repetitive surge peak on-state current (tp=20ms)		I _{TSM}	140	А



I ² t value for fusing (tp=10ms)		l ² t	98	A ² s
Critical rate of rise of on-state	I - II -III	dI/dt	50	A/µs
current (I _G =2×I _{GT})	IV		10	
Peak gate current	I _{GM}	2	Α	
Average gate power dissipation		P _{G(AV)}	0.5	W
Peak gate power		P _{GM}	5	W

ELECTRICAL CHARACTERISTICS (T_j =25 $^{\circ}$ C unless otherwise specified)

Symbol	Test Condition Quadr	Quadrant		Value				l loit
Symbol	rest Condition	Quadrant		D	E	F	В	Unit
I _{GT}	V _D =12V R _L =33Ω	I - II -III	MAX	5	10	25	50	mA
IGI		IV		10	25	70	70	
V _G T		ALL	MAX	1.3				٧
V _{GD}	$V_D=V_{DRM} T_j=125$ °C RL=3.3KΩ	ALL	MIN	0.2		٧		
IL	I _G =1.2I _{GT}	I - III	MAX	15	30	50	80	mA
		II - IV		20	40	100	120	
Ін	I _T =100mA		MAX	10	25	40	60	mA
dV/dt	V _D =2/3V _{DRM} Gate Open T _j =125℃		MIN	20	50	100	500	V/µs

STATIC CHARACTERISTICS

Symbol	Parameter		Value(MAX)	Unit
V _{TM}	I _{ТМ} =20A tp=380µs	Tj=25℃	1.6	V
I _{DRM}	\\-\\-\\-\\\-\\\-\\\-\\\-\\\-\\\-\\\-\	Tj=25℃	5	μA
I _{RRM}	VD=VDRM VR=VRRM	Tj=125℃	1	mA



THERMAL RESISTANCES

Symbol	Parameter		Value	Unit
Rth(j-c)	junction to case(AC)	TO-220C	1.2	- °C/W
		TO-220F(Ins)	2.3	
		TO-263	2.7	
		TO-220A(Ins)	2.1	



FIG.1 Maximum power dissipation versus RMS on-state current

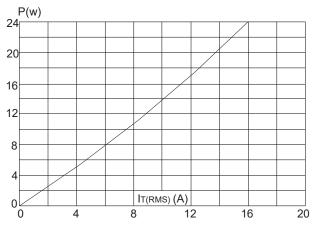


FIG.2: RMS on-state current versus case temperature

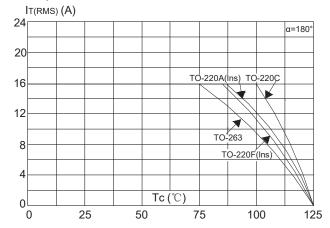




FIG.3: Surge peak on-state current versus number of cycles

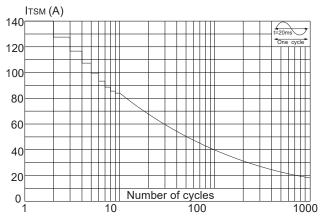


FIG.5: Non-repetitive surge peak on-state current for a sinusoidal pulse with width tp<20ms and corresponding value of I^2t (I - II - III : dI/dt < 50A/ μ s; IV:dI/dt < 10A/ μ s)

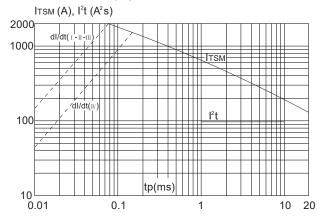


FIG.7: Relative variations of holding current versus junction temperature

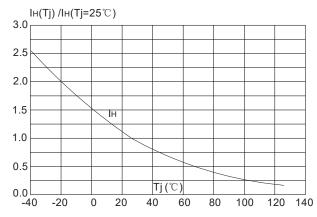


FIG.4: On-state characteristics (maximum values)

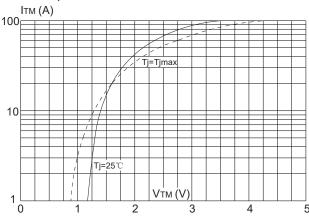


FIG.6: Relative variations of gate trigger current versus junction temperature

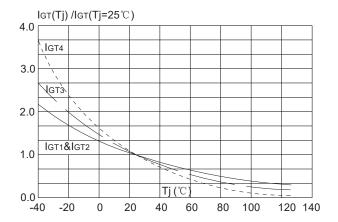


FIG.8: Relative variations of latching current versus junction temperature

